

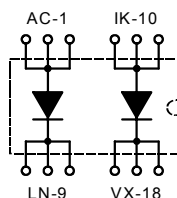
Fast Recovery Epitaxial Diode (FRED)

PSEI 2x161

$$\begin{aligned} I_{FAVM} &= 2 \times 165 \text{ A} \\ V_{RRM} &= 200 \text{ V} \\ t_{rr} &= 35 \text{ ns} \end{aligned}$$

Preliminary Data Sheet

V_{RSM} (V)	V_{RRM} (V)	Type
200	200	PSEI 2x161/02



Symbol	Test Conditions	Maximum Ratings
I_{FRMS}	$T_{VJ} = T_{VJM}$	270 A
I_{FAVM}^*	$T_C = 70^\circ\text{C}$, rectangular, $d=0.5$	165 A
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$ $t = 10 \text{ ms}$ (50 Hz), sine	1200 A
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	1300 A
	$T_{VJ} = 125^\circ\text{C}$ $t = 10 \text{ ms}$ (50 Hz), sine	1080 A
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	1170 A
$\int i^2 dt$	$T_{VJ} = 45^\circ\text{C}$ $t = 10 \text{ ms}$ (50 Hz), sine	7200 A ² s
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	7100 A ² s
	$T_{VJ} = 125^\circ\text{C}$ $t = 10 \text{ ms}$ (50 Hz), sine	5800 A ² s
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	5700 A ² s
T_{VJ}		-40... + 150 °C
T_{VJM}		150 °C
T_{stg}		-40... + 125 °C
V_{ISOL}	50/60 Hz, RMS $t = 1 \text{ min}$	2500 V~
	$I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$	3600 V~
M_d	Mounting torque (M4)	1.5 - 2.0 Nm
		14 - 18 lb.in.
Weight	typ.	24 g

Symbol	Test Conditions	Characteristic Value
I_R	$T_{VJ} = 25^\circ\text{C}$, $V_R = V_{RRM}$	max. 3 mA
	$T_{VJ} = 25^\circ\text{C}$, $V_R = 0.8 \cdot V_{RRM}$	max. 2 mA
	$T_{VJ} = 125^\circ\text{C}$, $V_R = 0.8 \cdot V_{RRM}$	max. 80 mA
V_F	$I_F = 200 \text{ A}$, $T_{VJ} = 25^\circ\text{C}$	max. 1.20 V
V_{TO}	For power-loss calculations only	0.53 V
r_T		2.6 mΩ
R_{thJC}	per diode; max.	0.29 K/W
R_{thCH}	per diode; typ.	0.2 K/W
I_{RM}	$I_F = 100 \text{ A}$; $-di_F/dt = 200 \text{ A}/\mu\text{s}$; $V_R = 100 \text{ V}$ $L \leq 0.05 \text{ mH}$; $T_{VJ} = 100^\circ\text{C}$	typ. 20 A
t_{rr}	$I_F = 1 \text{ A}$; $-di_F/dt = 400 \text{ A}/\mu\text{s}$; $V_R = 30 \text{ V}$; $T_{VJ} = 25^\circ\text{C}$	typ. 35 ns
d_s	Creeping distance on surface	11.2 mm
d_A	Creeping distance in air	11.2 mm
a	Max. allowable acceleration	50 m/s ²

Features

- 2 independent FRED in 1 package
- Isolation voltage 3600 V~
- Planar glass passivated chips
- Low forward voltage drop
- Leads suitable for PC board soldering
- Very short recovery time
- Soft recovery behaviour
- UL registered, E 148688

Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability
- Low noise switching
- Small and light weight

Data according to IEC 60747 refer to a single diode unless otherwise stated

* I_{FAVM} rating includes blocking losses at T_{VJM} ;
 $V_R = 0.8 V_{RRM}$; duty cycle $d = 0.5$

Dimensions in mm (1mm = 0.0394")

